TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7WG74FC

#### D-Type Flip Flop with Preset and Clear

#### **Features**

• High-speed : f<sub>MAX</sub> = 246 MHz (Typ.)

at  $V_{CC} = 3 \text{ V}$ , CL=15pF

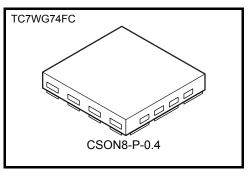
High-level output current: : I<sub>OH</sub>/I<sub>OL</sub> = ±8 mA (min)

at  $V_{CC} = 3 V$ 

• Operation voltage range : V<sub>CC</sub>(opr)=0.9~3.6V

• 5.5-V tolerant inputs

• 3.6-V power down protection outputs



Weight: 0.002g (typ.)

### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit
Power supply voltage	V <sub>CC</sub>	-0.5~4.6	V
DC input voltage	V <sub>IN</sub>	-0.5~7.0	V
DO autout well-	V	-0.5~4.6 (Note 1)	V
DC output voltage	V <sub>OUT</sub>	-0.5~V <sub>CC</sub> + 0.5 (Note 2)	V
Input diode current	I <sub>IK</sub>	-20	mA
Output diode current	lok	-20 (Note 3)	mA
DC output current	lout	±25	mA
DC V <sub>CC</sub> /GND current	Icc	±100	mA
Power dissipation	PD	150 (Note 4)	mW
Storage temperature	T <sub>stg</sub>	-65~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V<sub>CC</sub> = 0V

Note 2: High or Low State.

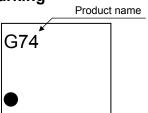
 $I_{\mbox{\scriptsize OUT}}$  absolute maximum rating must be observed.

Note 3: V<sub>OUT</sub> < GND

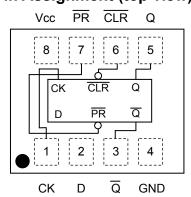
Note 4: Mounted on an FR4 board.

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ t}, \text{ Cu Pad: } 11.56 \text{ mm}^2)$ 

#### Marking



#### Pin Assignment (top view)

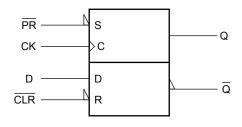


## **Truth Table**

	Inn	uts		Out	puts			
			011			Function		
CLR	PR	D	CK	Q	Q			
L	Η	X	Х	L	Ι	Clear		
Н	L	X	Х	Н	L	Preset		
L	L	Х	Х	Н	Н	_		
Н	Н	L		L	Н	_		
Н	Н	Н	<b>_</b>	Н	L			
Н	Н	Х	7_	Qn	Qn	No Change		

X : Don't Care

## IEC Logic Symbol



TC7WG74FC



### **Operating Ranges**

Characteristics	Symbol	Value	Unit		
Power supply voltage	V <sub>CC</sub>	0.9~3.6	V		
Input voltage	V <sub>IN</sub>	0~5.5	V		
Output voltage	V	0~3.6 (Note 5)	V		
	V <sub>OUT</sub>	0~V <sub>CC</sub> (Note 6)	V		
		±8.0 (Note 7)			
		±4.0 (Note 8)			
Outrout Course at		±3.0 (Note 9)	A		
Output Current	I <sub>OH</sub> /I <sub>OL</sub>	±1.7 (Note 10)	mA		
		±0.3 (Note 11)			
		±0.02 (Note 12)			
Operating temperature	T <sub>opr</sub>	−40 <b>~</b> 85	°C		
Input rise and fall time	dt/dV	0~10 (Note 13)	ns/V		

Note 5:  $V_{CC} = 0V$ 

Note 6: High or Low state.

Note 7:  $V_{CC} = 3.0 \sim 3.6 \text{ V}$ 

Note 8:  $V_{CC} = 2.3 \sim 2.7 \text{ V}$ 

Note 9:  $V_{CC} = 1.65 \sim 1.95 \text{ V}$ 

Note 10: V<sub>CC</sub> = 1.4~1.6 V

Note 11: V<sub>CC</sub> = 1.1~1.3 V

Note 12:  $V_{CC} = 0.9 \text{ V}$ 

Note 13:  $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$ 

## **DC Electrical Characteristics**

Characteristics	Symbol	Tost	Condition		1	Γa = 25°(	)	Ta = -4	Unit		
Characteristics	Symbol	1630	Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic	
				0.9	$V_{CC}$		_	V <sub>CC</sub>	_		
				1.1~1.3	V <sub>CC</sub> × 0.7		_	V <sub>CC</sub> × 0.7	_		
High-level VIH		_		V <sub>CC</sub> × 0.65	_	_	V <sub>CC</sub> × 0.65	_	V		
input voltage				1.65~1.95	V <sub>CC</sub> × 0.65	_	_	V <sub>CC</sub> × 0.65	_		
				2.3~2.7	1.7	_	_	1.7	_		
				3.0~3.6	2.0	_	_	2.0	_		
				0.9			GND	_	GND		
				1.1~1.3	ı	١	V <sub>CC</sub> × 0.3		V <sub>CC</sub> × 0.3		
Low-level	Low-level V <sub>IL</sub>		_	1.4~1.6	l		V <sub>CC</sub> × 0.35		V <sub>CC</sub> × 0.35	V	
input voltage					ı	١	V <sub>CC</sub> × 0.35		V <sub>CC</sub> × 0.35		
				2.3~2.7			0.7		0.7		
					_	0.8		0.8			
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> =-0.02 mA	0.9	0.75	_	_	0.75	_		
			$I_{OH} = -0.3 \text{ mA}$	1.1~1.3	V <sub>CC</sub> × 0.75		_	V <sub>CC</sub> × 0.75	_		
High-level	V <sub>OH</sub>		$I_{OH} = -1.7 \text{ mA}$	1.4~1.6	V <sub>CC</sub> × 0.75		_	V <sub>CC</sub> × 0.75	_	V	
output voltage			I <sub>OH</sub> = -3.0 mA	1.65~ 1.95	V <sub>CC</sub> -0.45	_	_	V <sub>CC</sub> -0.45	_	_	
			I <sub>OH</sub> = -4.0 mA	2.3~2.7	2.0	_	_	2.0	_		
			$I_{OH} = -8.0 \text{ mA}$	3.0~3.6	2.48	_	_	2.48	_		
			$I_{OL} = 0.02 \text{ mA}$	0.9			0.1	_	0.1		
			I <sub>OL</sub> = 0.3 mA	1.1~1.3			V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25		
Low-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OL</sub> = 1.7 mA	1.4~1.6	_	_	V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25	V	
output voltage		or V <sub>IL</sub>	I <sub>OL</sub> = 3.0 mA	1.65~ 1.95		_	0.45	_	0.45		
			I <sub>OL</sub> = 4.0 mA	2.3~2.7	_	_	0.4	_	0.4		
			I <sub>OL</sub> = 8.0 mA	3.0~3.6			0.4	_	0.4		
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 0~5.5		0~3.6	_	_	±0.1	_	±1.0	μА	
Power off leakage current	I <sub>OFF</sub>	V <sub>IN</sub> = 0~5.5 V <sub>OUT</sub> = 0~3	5V 3.6V	0.0	_	_	1.0	_	10.0	μА	
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub>	or GND	3.6	l	_	1.0	_	10.0	μА	

## Timing Requirements (Input: $t_r = t_f = 3 \text{ ns}$ )

Characteristic	Symbol Test cor		ndision	Ta = 25°C			Ta = -40~85°C		Unit
Characteristic	Symbol	Symbol		Min.	Тур.	Max.	Min.	Max.	Offic
			0.9	_	26.4	_	_	_	
			1.1~1.3	12.4	_	_	22.7	_	
Pulse width	t <sub>W(L)</sub>		1.4~1.6	5.5	_	_	6.7	_	
( CK )	t <sub>W(H)</sub>		1.65~ 1.95	4.3	_	_	4.7	_	
			2.3~2.7	3.5	_	_	3.5	_	
			3.0~3.6	3.2	_	_	3.2	_	
			0.9	_	22.8	_	_	_	
			1.1~1.3	11.6	_	_	20.4	_	
Pulse width			1.4~1.6	5.3	_	_	6.5	_	
( $\overline{CLR}$ , $\overline{PR}$ )	t <sub>W(L)</sub>		1.65~ 1.95	4.2	_	_	4.6	_	
			2.3~2.7	3.3	_	_	3.3	_	
		3.0~3.6	3.2	_	_	3.2	_		
	ts		0.9	_	31.9	_	_	_	
			1.1~1.3	14.4	_	_	21.7	_	
Sot up time		1.4~1.6	6.4	_	_	7.2	_	ns	
Set-up time			1.65~ 1.95	4.4	_	_	4.8	_	110
			2.3~2.7	2.5	_	_	2.9	_	
			3.0~3.6	1.9	_	_	2.3	_	
			0.9	_	0.5	_	_	_	
			1.1~1.3	0.1	_	_	0.1	_	
Hold time	t <sub>i</sub> .		1.4~1.6	0.1	_	_	0.1	_	
Tiola time	t <sub>h</sub>		1.65~ 1.95	0.1	_	_	0.1	_	
			2.3~2.7	0.1	_	_	0.1	—	
			3.0~3.6	0.1	_	_	0.1	_	
			0.9	_	17.9	_	_	—	
			1.1~1.3	8.6	—	—	13	—	
Removal time	t <sub>rem</sub>		1.4~1.6	3.9	_	_	4.4	_	
(CLR, PR)	чет		1.65~ 1.95	2.6	—	—	3.1	—	
			2.3~2.7	1.5	_	_	1.9	_	
				1.2	_	_	1.5	_	

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## AC Electrical Characteristics (Input: $t_r = t_f = 3 \text{ ns}$ )

		Test condition		-	Γa = 25°(		Ta = -40~85°C		
Characteristic	Symbol		V <sub>CC</sub> (V)	Min.	Тур.	Max.	Min.	Max.	Unit
			0.9	_	36.6	_	1.0	_	
			1.1~1.3	_	15.7	23.2	1.0	34.6	
		CL = 10 pF	1.4~1.6	_	8.0	10.5	1.0	11.5	
		CL = 10 pr	1.65~1.95	_	5.9	7.4	1.0	7.9	
			2.3~2.7	_	3.8	4.7	1.0	5.1	
			3.0~3.6	_	3.0	3.8	1.0	4.2	
			0.9	_	40.8	_	1.0	_	
			1.1~1.3	_	17.1	25.3	1.0	38.5	
	t <sub>pLH</sub>	CL = 15 pF	1.4~1.6	_	8.8	11.5	1.0	12.7	ns
Propagation deley time $(CK - Q, \overline{Q})$	t <sub>pHL</sub>	CL = 15 pr	1.65~1.95	_	6.4	8.1	1.0	8.6	115
(CK - Q, Q)			2.3~2.7	_	4.1	5.1	1.0	5.5	
			3.0~3.6	_	3.3	4.1	1.0	4.5	
			0.9		54.8	1	1.0	_	
		CL = 30 pF	1.1~1.3		22.6	34.7	1.0	54.4	
			1.4~1.6		11.4	15.0	1.0	16.8	
			1.65~1.95		8.2	10.3	1.0	10.8	
			2.3~2.7	_	5.2	6.3	1.0	6.6	
			3.0~3.6		4.1	5.0	1.0	5.3	
			0.9	_	46.9	_	1.0	_	
			1.1~1.3		18.8	27.8	1.0	45.2	
		CL = 10 pF	1.4~1.6	_	9.5	12.4	1.0	14.0	
			1.65~1.95		6.9	8.7	1.0	9.1	
			2.3~2.7		4.3	5.3	1.0	5.7	
			3.0~3.6		3.3	4.2	1.0	4.6	
			0.9		50.1		1.0	_	1
			1.1~1.3		20.2	29.8	1.0	49.4	
Dranagation delay time	t <sub>pLH</sub>	CL = 15 pF	1.4~1.6		10.1	13.2	1.0	15.1	ns
Propagation deley time ( CLR , PR – Q , Q )	t <sub>pHL</sub>	OL = 15 pi	1.65~1.95		7.3	9.2	1.0	9.7	113
(OLN, FN - Q, Q)			2.3~2.7		4.5	5.6	1.0	6.2	
			3.0~3.6		3.6	4.5	1.0	4.9	
			0.9	_	64.4	_	1.0	_	
			1.1~1.3	_	25.6	39.2	1.0	64.6	
		CL = 30 pF	1.4~1.6	-	12.6	16.8	1.0	19.1	
		CL = 30 pF	1.65~1.95	-	9.0	11.3	1.0	11.8	
			2.3~2.7	_	5.6	6.8	1.0	7.1	
			3.0~3.6		4.4	5.3	1.0	5.6	

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### AC Electrical Characteristics (Input: $t_r = t_f = 3 \text{ ns}$ )

		Test condition		Ta = 25°C			Ta = -40~85°C		
Characteristic	Symbol		V <sub>CC</sub> (V)	Min.	Тур.	Max.	Min.	Max.	Unit
			0.9		14	_		_	
			1.1~1.3	22	35		14		
		CL = 10 pF	1.4~1.6	57	75		51		
		OL - 10 βi	1.65~1.95	90	111		84		
			2.3~2.7	169	194		145	1	
			3.0~3.6	233	254		200		
	f <sub>MAX</sub>	CL = 15 pF	0.9		13		_		MHZ
			1.1~1.3	20	32	_	13		
Ola ala faranza ara			1.4~1.6	59	74	_	48	_	
Clock frequency			1.65~1.95	84	104	_	80	_	
			2.3~2.7	156	179	_	139	_	
			3.0~3.6	225	246	_	189	_	
			0.9	_	14	_	_	_	
			1.1~1.3	17	30	_	11	_	
		CL = 30 pF	1.4~1.6	45	63	_	39	_	
		CL = 30 pr	1.65~1.95	71	91	_	68	_	
			2.3~2.7	135	159	_	120	_	
			3.0~3.6	189	214		163		
Input capacitance	C <sub>IN</sub>	_	3.6	_	3	_	_		pF
Power dissipation capacitanse	C <sub>PD</sub>	(Note 14)	0.9~3.6		14	_	_	_	pF

Note 14 : C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

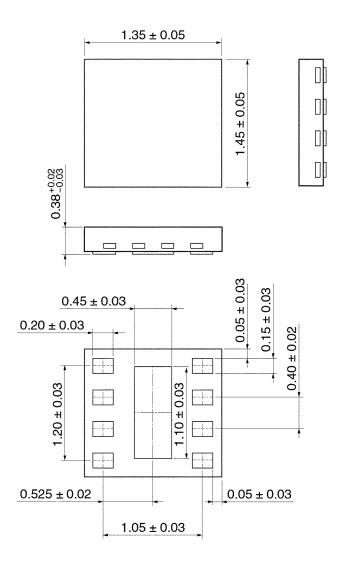
Average operating current can be obtained by the equation:

 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 



## **Package Dimensions**

CSON8-P-0.4 Unit: mm



Weight: 0.002 g (Typ.)

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20070701-EN GENERAL

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